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Semiconductor Device. Silicon because its tolerance is high
P-N junction (or Semiconductor diode) Eg:- Germanium

Semiconductor having half pentavalent doping and half trivalent doping is known as P-N junction.

The region where the two doped region meet is called P-N junction. At the instant of junction formation, free electron on N-side drift towards P-side and near



depletion region

fig (1)

and near the junction they combine and there are some region near the junction gets depleted from holes and free electrons. This region is called depletion region. Potential difference developed across depletion region is called potential barrier denoted by V_B . Its value is 0.3 eV for (Si) diode and 0.7 volt for (Ge) diode.

Fig (2) shows the circuit symbol of P-N diode.



fig (2)

Characteristics curve for P-N diode.

Connection of battery in a circuit is called biasing.

- 4) If positive terminal of battery is connected to P-side and negative terminal of battery is connected to N-side then it is called forward biasing.
- 4) If positive terminal of battery is connected to N-side and negative terminal of battery is connected to P-side then it is called negative biasing.

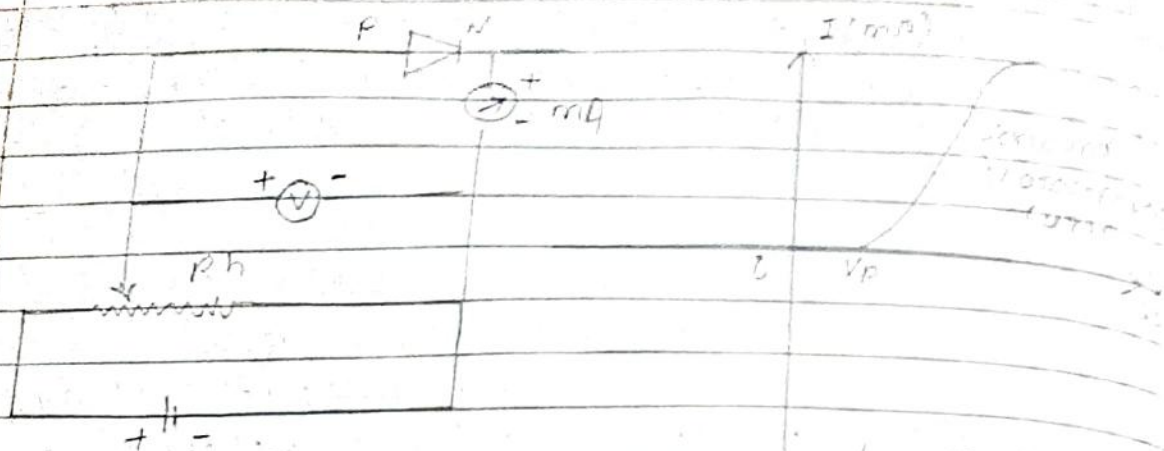


fig (1) forward biased diode

fig (2)

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Fig (1) shows the circuit diagram of forward biased diode and fig (2) shows the voltage current graph which is forward characteristics curve. Initially when forward voltage (V) increases the current does not flow in the circuit. At a certain voltage V_k the current starts flowing in the circuit. This voltage V_k is known as knee voltage.

Fig (3) below shows the circuit diagram to draw reverse characteristics of PN diode and fig (4) shows reverse characteristics.

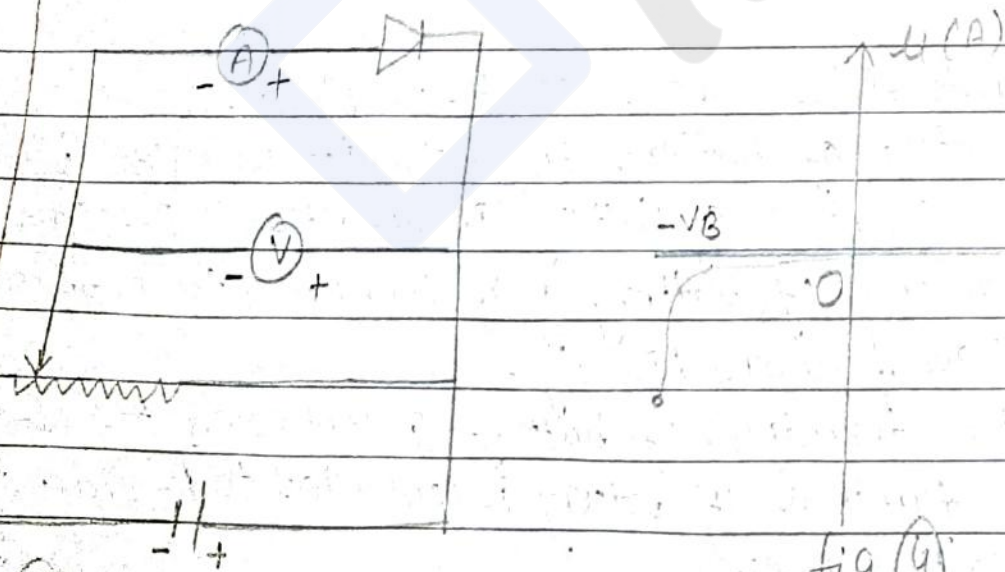


fig (3)

fig (4)

Breakdown: The reverse current is very small but as the reverse voltage reaches its peak, within a very short time, current suddenly increases due to breaking of covalent bonds by very high electric field. This voltage is known as break down voltage.

→ (PN diode is never used as rectifier because it gets fused / damaged due to very high current)

Application of PN junction diode as rectifier -

The electronic circuit that converts AC into

DC is known as rectifier.

① Half wave rectifier

When 1 PN diode is connected to the output of a transformer then only half wave of input AC is rectified and the circuit is known as half wave rectifier. Fig (a) shows the circuit diagram of half wave rectifier. Fig (b) shows the input and output voltages.

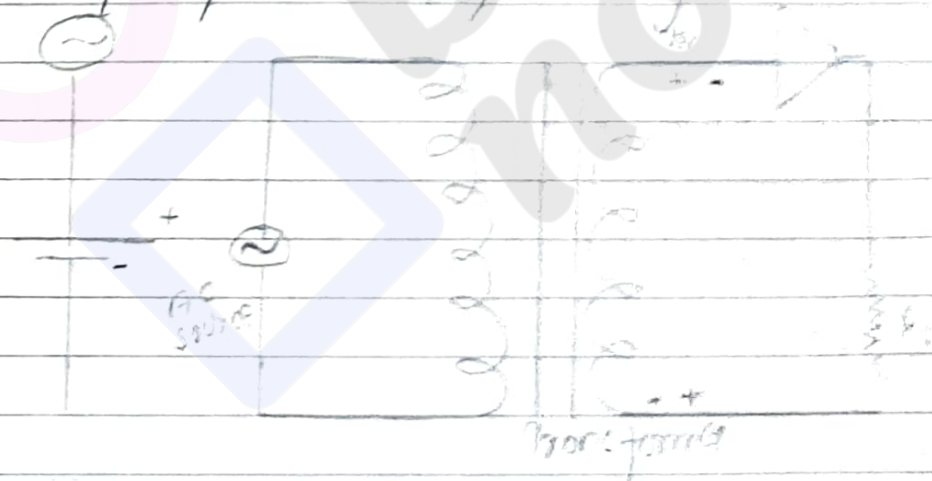


Fig ① Circuit of HWR

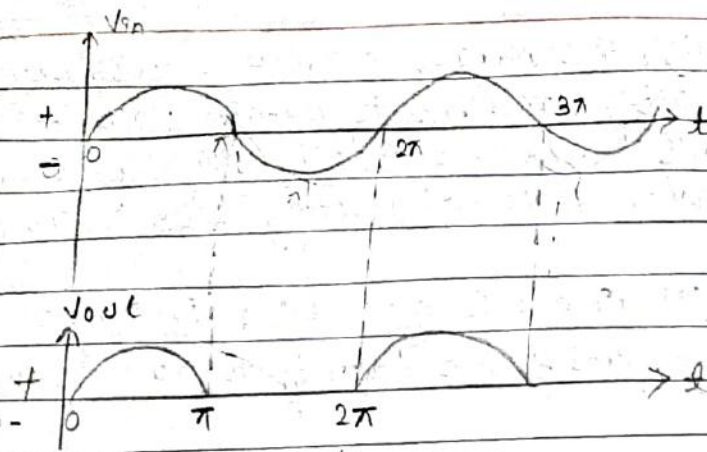


fig ②

During +ve half cycle of input AC if upper end of secondary of transformer is +ve and lower end is -ve then diode is forward biased from 0 to π of input, hence diode conducts from 0 to π in load resistance R_L . During next

During next -ve half cycle the polarity reverses and diode gets reverse biased hence does not conduct for π to 2π and soon. Hence the output has half wave unidirectional (i.e. rectified)

② Full wave rectifier (FWR) :- (2-diode).

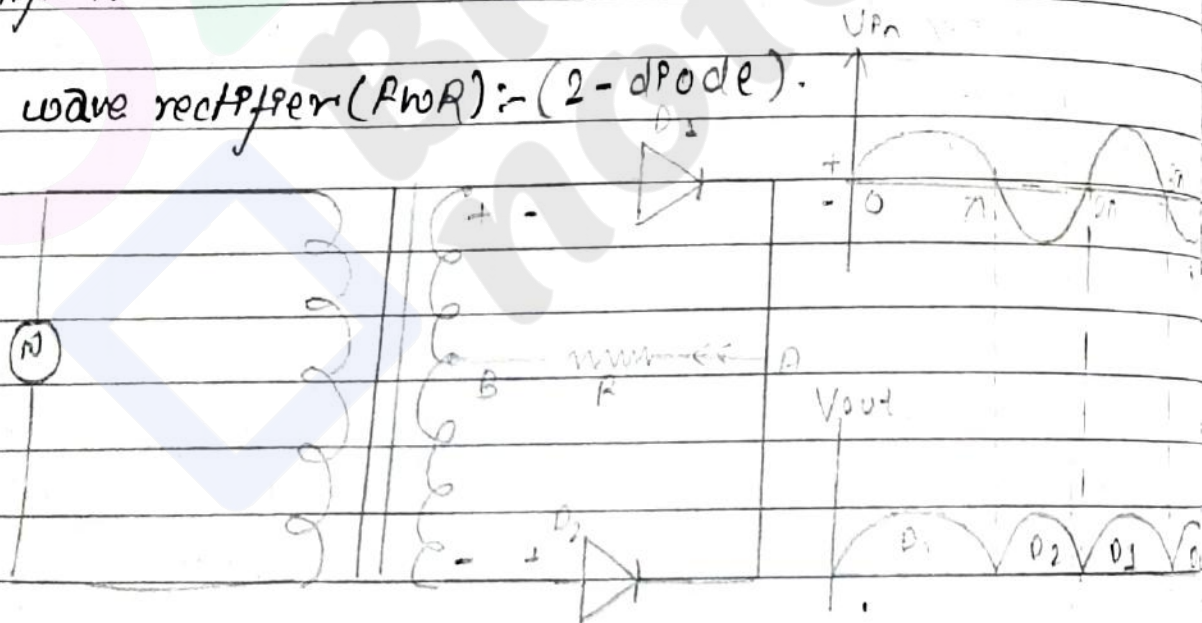


fig ③ circuit of full wave rectifier.

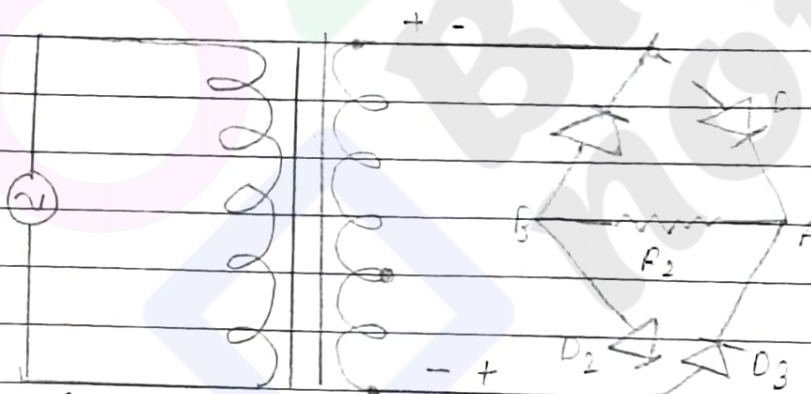
fig ④ Input and output of full wave rectifier

fig(3) shows full wave rectifier using 4 connected two diode D_1 and D_2 and fig(4) shows the input and output signals of full wave rectifier.

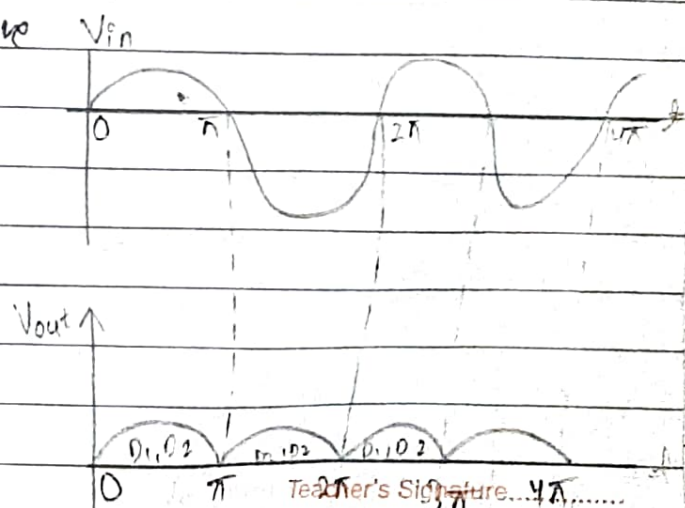
During the +ve half cycle of input AC. Let the upper end of secondary of transformer is +ve and lower end is -ve. Then diode (D_1) will be forward biased and will conduct through load resistance along AB. while diode (D_2) is in reversed biased does not conduct. For the next -ve half cycle the polarity reverses, D_2 gets forward biased and conduct through load resistance (R_L) along AB while diode D_1 being reversed biased does not conduct from π to 2π and so on.

Thus, the output has full wave rectified (i.e. unidirectional).

* Full wave bridge rectifier :



fig(5) circuit of full wave bridge rectifier.



DC \rightarrow AC \rightarrow DC
AC \rightarrow DC = rectifier

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In full wave rectifier, 4 diodes D_1, D_2, D_3, D_4 are connected to the secondary of transformer along with resistance R_L in the form of a bridge as shown in fig.

During the half cycle of input AC if upper end of secondary of transformer is +ve and lower end is -ve then D_1, D_2 get forward biased and conduct through R_L along AB. D_3, D_4 being reversed biased do not conduct.

Now, in the next -ve half cycle of input AC polarity reverses making D_3, D_4 forward biased and D_1, D_2 reverse biased. So, D_3, D_4 conduct through R_L along AB and D_1, D_2 do not conduct.

Thus output is unidirectional (i.e. rectifier).

Logic gates:-

The electronic circuit that gives the output corresponding to different input is called logic gates. It can have one or more inputs but only one output.

OR gate:-

OR gate has two or more inputs but only one output. The output is high (1) when one or more inputs are high. Fig (1) below shows the logic symbol of two input OR gate and table (2) shows its truth table.

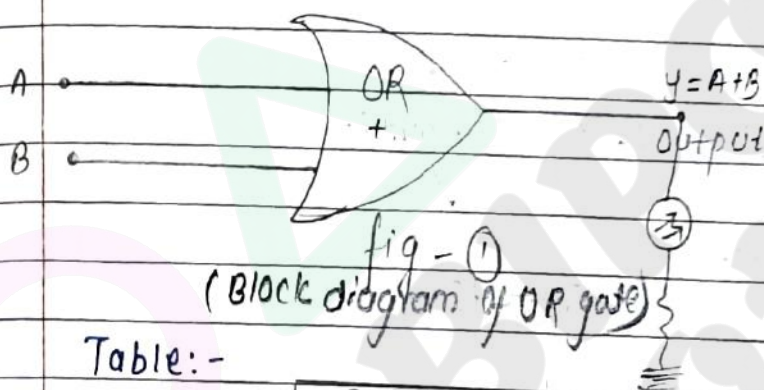


Table:-

Inputs		Outputs
A	B	
0	0	0
0	1	1
1	0	1
1	1	1

AND gate:-

And gate is a logic gate that can have two or more inputs but only one output. The output is high only when all inputs are high.

Fig ① shows the block diagram of two input AND gate and Table 1 shows its truth table.

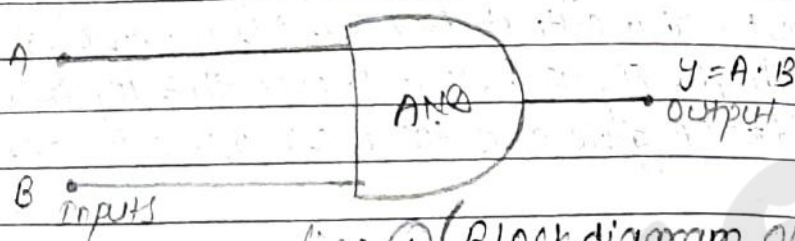


fig:- ① (Block diagram of AND gate)

Table 1; Truth Table of AND gate:-

Inputs		Outputs
A	B	
0	0	0
0	1	0
1	0	0
1	1	1

NOT gate:-

NOT gate is a logic gate which has one input and only one output. The output is the inverted input.

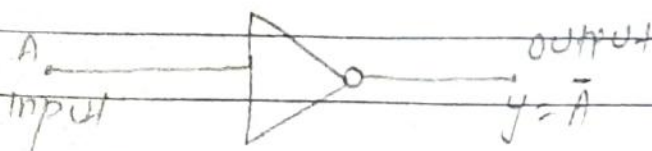


fig ② Block diagram of NOT gate.

Table 2: Truth table of NOT gate:-

Input A	Output $y = \bar{A}$
0	1
1	0

* NAND GATE:-

AND gate followed by NOT gate is called NAND gate. It may have two or more inputs but only one output is. - The output is low only when all inputs are high (1).
fig (3) shows the block diagram of two inputs NAND GATE and table (3) shows its truth table.

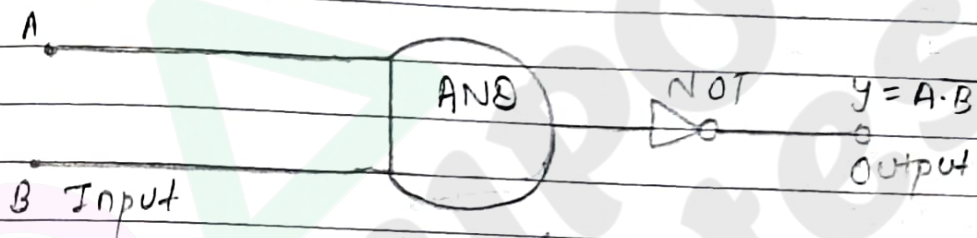


fig- 3 (Block diagram of NAND GATE)

Table 3: Truth table of NAND GATE.

Inputs		Output
A	B	
0	0	1
0	1	1
1	0	1
1	1	0

NOR GATE:- OR gate followed by NOT gives or called NOR gate. It may have two more inputs but only one output

fig (4) shows block diagram of two inputs NOR gate and table (4) shows its truth table.

Output is high ^{only} when all inputs are low.

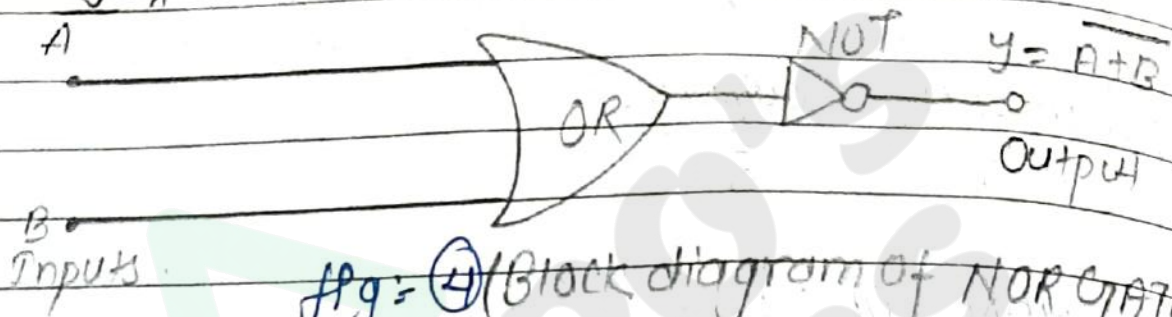


Fig: ④ (Block diagram of NOR GATE)

Table 4:- Truth Table of NOR GATE.

Inputs		Outputs
A	B	
0	0	1
0	1	0
1	0	0
1	1	0